

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No.10/636,038
Confirmation No.9972
Filing DateAugust 6, 2003
Inventor.....Gurtej S. Sandhu
AssigneeMicron Technology, Inc.
Group Art Unit.....1762
ExaminerChen, Bret P.
Attorney's Docket No.MI22-2194
Customer No.021567
Title: Methods of Forming Material on a Substrate, and Method of Forming a
Field Effect Transistor Gate Oxide on a Substrate

RESPONSE TO NOVEMBER 28, 2006 FINAL OFFICE ACTION

To: Mail Stop AF
Commissioner for Patents
P.O. Box 1450
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AMENDMENTS

In response to the Final Office Action of November 28, 2006, applicant amends and
remarks as follows.